

Features

- Low RDS(on)
- Operated at Low Logic Level Gate Drive
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 833°C/W Junction to Ambient^(Note 2)
- Thermal Resistance: 277°C/W Junction to Lead^(Note 2)

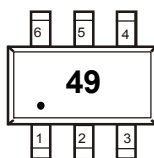
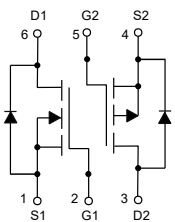
Parameter	Symbol	Rating	Unit
Total Power Dissipation	P_D	450	mW
N-Channel MOSFET			
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	±10	V
Continuous Drain Current	I_D	1.5	A
Pulsed Drain Current ^(Note 3)	I_{DM}	6	A
P-Channel MOSFET			
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	±10	V
Continuous Drain Current	I_D	-1	A
Pulsed Drain Current ^(Note 3)	I_{DM}	-4	A

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

2. Surface Mounted on FR-4 Board Using Minimum Pad Size.

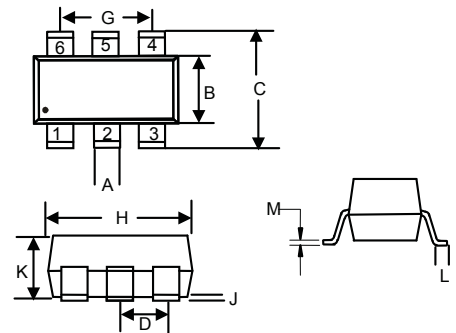
3. Pulse Width Limited by Maximum Junction Temperature.

Internal Structure and Marking Code



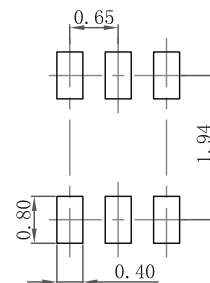
Dual N&P-Channel MOSFET

SOT-363



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.006	0.014	0.15	0.35	
B	0.045	0.053	1.15	1.35	
C	0.079	0.096	2.00	2.45	
D	0.026		0.65		TYP.
G	0.047	0.055	1.20	1.40	
H	0.071	0.087	1.80	2.20	
J	----	0.004	----	0.10	
K	0.031	0.043	0.80	1.10	
L	0.010	0.018	0.26	0.46	
M	0.003	0.006	0.08	0.15	

Suggested Solder Pad Layout



N-Channel MOSFET Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	20			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 10V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=20V, V_{GS}=0V$			1	μA
Gate-Threshold Voltage ^(Note4)	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.55		1.1	V
Drain-Source On-Resistance ^(Note4)	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=1.0A$			90	m Ω
		$V_{GS}=2.5V, I_D=0.6A$			105	m Ω
		$V_{GS}=1.8V, I_D=0.3A$			154	m Ω
Diode Forward Voltage ^(Note4)	V_{SD}	$V_{GS}=0V, I_S=1.5A$			1.2	V
Dynamic Characteristics^(Note5,6)						
Input Capacitance	C_{iss}	$V_{DS}=10V, V_{GS}=0V, f=1MHz$		202		pF
Output Capacitance	C_{oss}			37		
Reverse Transfer Capacitance	C_{rss}			29		
Total Gate Charge	Q_g	$V_{DS}=4.5V, V_{GS}=10V, I_D=1.5A$		2.98		nC
Gate-Source Charge	Q_{gs}			0.72		
Gate-Drain Charge	Q_{gd}			0.59		
Reverse Recovery Charge	Q_{rr}	$I_{SD}=1.5A, di/dt=100A/us$		0.9		
Reverse Recovery Time	T_{rr}			9		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=4.5V, V_{DS}=10V, I_{DS}=1.5A, R_G=3\Omega,$		3		ns
Turn-On Rise Time	t_r			22		
Turn-Off Delay Time	$t_{d(off)}$			13.2		
Turn-Off Fall Time	t_f			22		

P-Channel MOSFET Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-20			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 10V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-20V, V_{GS}=0V$			-1	μA
Gate-Threshold Voltage ^(Note4)	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.4		-1.0	V
Drain-Source On-Resistance ^(Note4)	$R_{DS(on)}$	$V_{GS}=-4.5V, I_D=-1.0A$			150	m Ω
		$V_{GS}=-2.5V, I_D=-0.6A$			180	m Ω
		$V_{GS}=-1.8V, I_D=-0.3A$			260	m Ω
Diode Forward Voltage ^(Note4)	V_{SD}	$V_{GS}=0V, I_S=-0.5A$			-1.2	V
Dynamic Characteristics^(Note5,6)						
Input Capacitance	C_{iss}	$V_{DS}=-10V, V_{GS}=0V, f=1MHz$		223		pF
Output Capacitance	C_{oss}			35		
Reverse Transfer Capacitance	C_{rss}			33		
Total Gate Charge	Q_g	$V_{DS}=-4.5V, V_{GS}=-10V, I_D=-1A$		3		nC
Gate-Source Charge	Q_{gs}			0.75		
Gate-Drain Charge	Q_{gd}			0.55		
Reverse Recovery Charge	Q_{rr}	$I_{SD}=-1A, di/dt=100A/us$		0.9		
Reverse Recovery Time	T_{rr}			5.9		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=-4.5V, V_{DS}=-10V, I_{DS}=-1A, R_G=3\Omega,$		6		ns
Turn-On Rise Time	t_r			9		
Turn-Off Delay Time	$t_{d(off)}$			22		
Turn-Off Fall Time	t_f			17.2		

Note 4. Pulse Test : Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.

5. Switching characteristics are independent of operating junction temperature.

6. Guaranteed by Design, Not Subject to Production Testing.

Curve Characteristics(N-Channel)

Fig. 1 - Output Characteristics

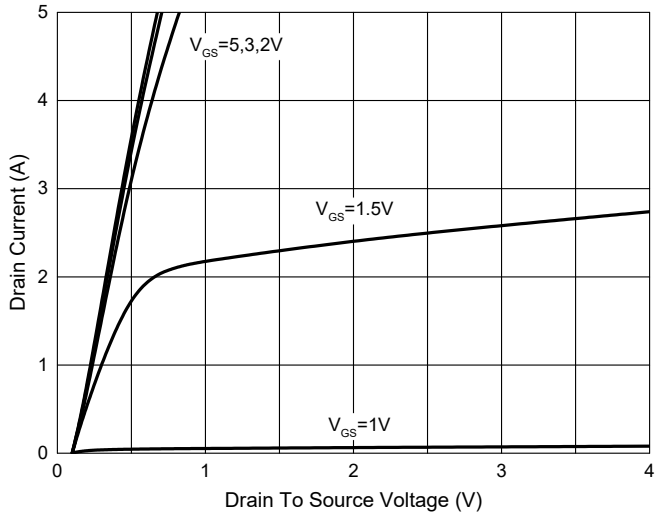


Fig. 2 - Transfer Characteristics

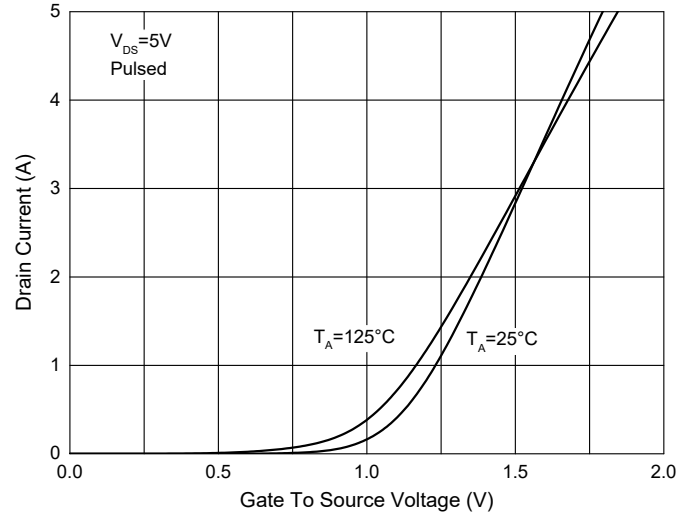


Fig. 3 - $R_{DS(ON)} - I_D$

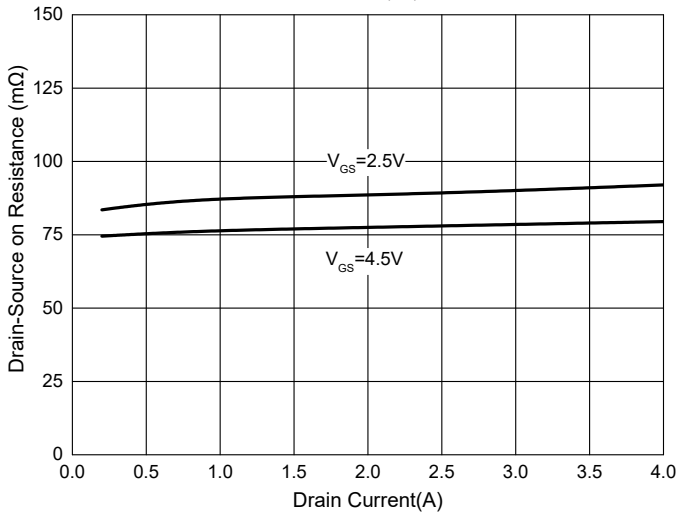


Fig. 4 - Normalized On Resistance Characteristics

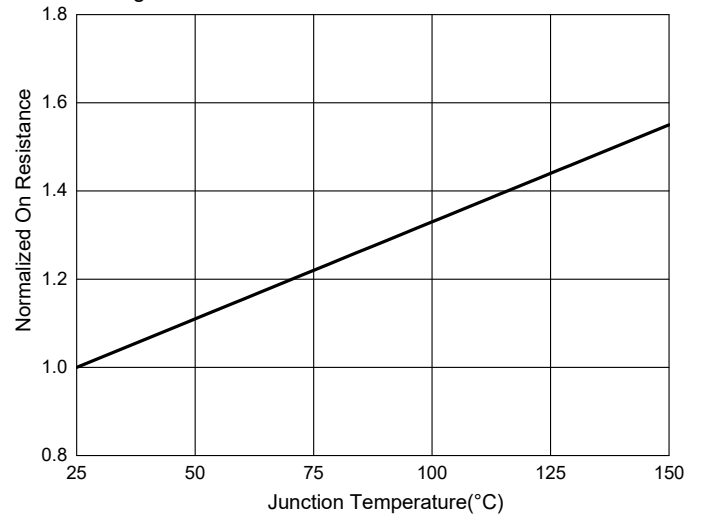


Fig. 5 - Gate Charge

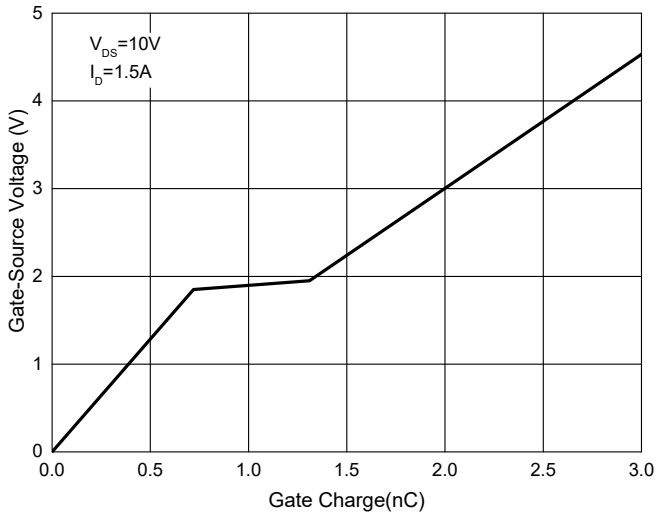
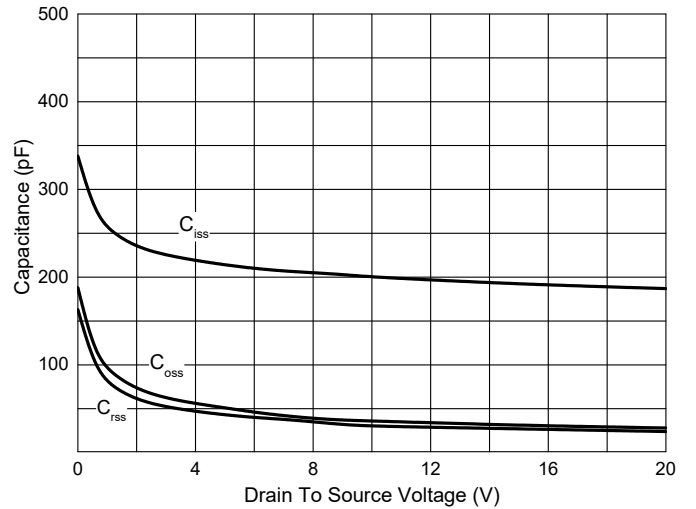


Fig. 6 - Capacitance Characteristics



Curve Characteristics(P-Channel)

Fig. 7 - Output Characteristics

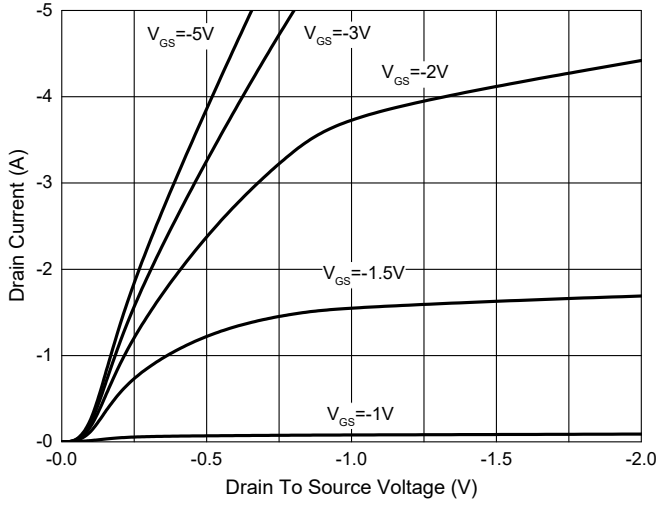


Fig. 8 - Transfer Characteristics

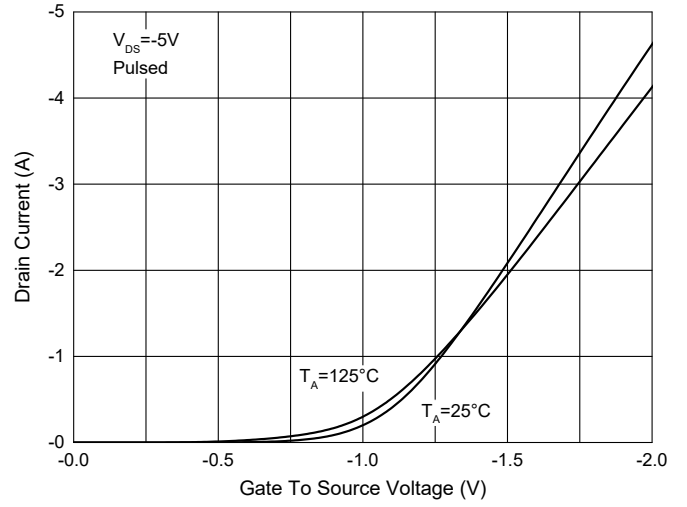


Fig. 9 - $R_{DS(ON)} - I_D$

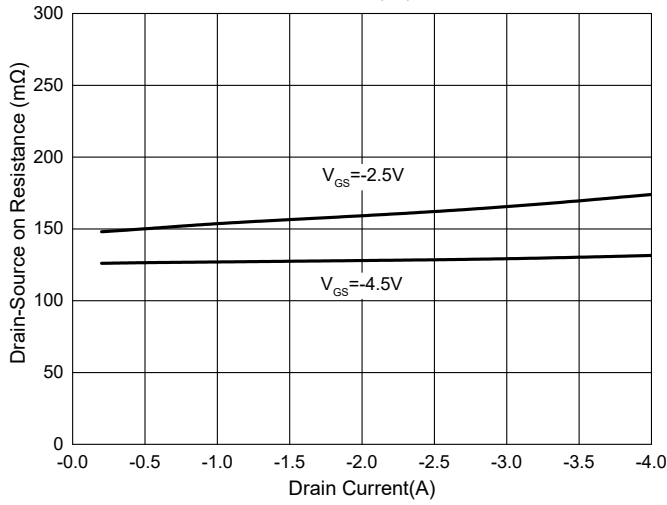


Fig. 10 - Normalized On Resistance Characteristics

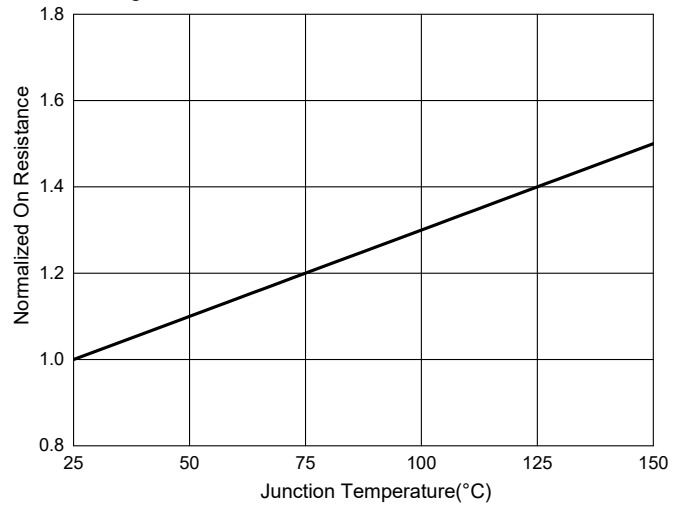


Fig. 11 - Gate Charge

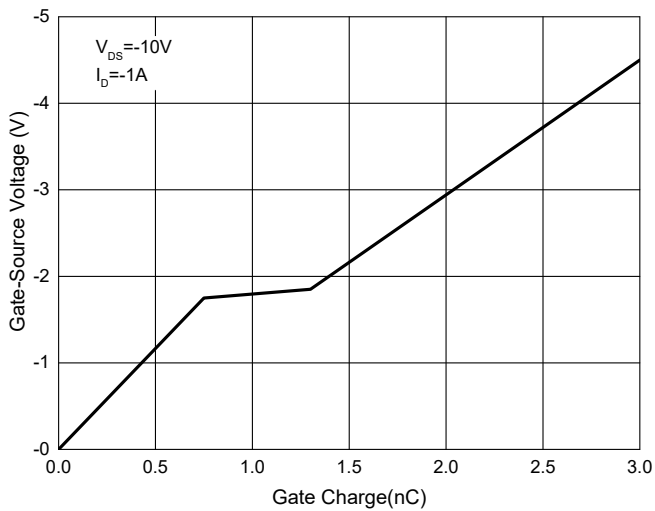
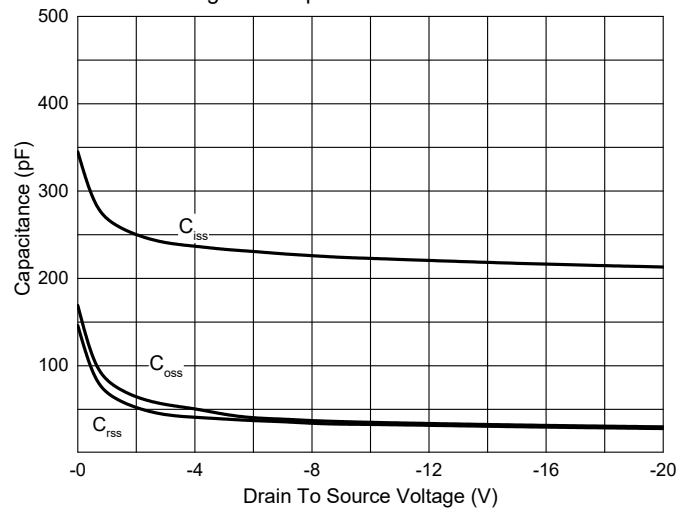


Fig. 12 - Capacitance Characteristics



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

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